# A band-free approach to twistronics

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# Modeling moiré systems

Semimetals:

Semiconductors:





# Modeling moiré systems

Semimetals:



Problem: Materials with multiple bands, metallic regionsGoal: Predict twistronic effects in any spectral environmentHow: Look at stacking-dependent local density of states

Semiconductors:



# 1D moire model



 $T(\mathbf{d}) = T_1 e^{-(d/\xi)^2}$ 

#### LDoS (arb. units)



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 $T_1 = T_0$ 

Energy  $(T_0)$ 



 $\mathbf{d}$  L 0

Increased interlayer coupling range: Stronger average coupling Weaker variation



 $T_1 = 3T_0$ 

0 d L







Harmonic oscillator flat bands  
$$H = \frac{1}{2m^*} (\psi_1^{\dagger} \partial^2 \psi_1 + \psi_2^{\dagger} \partial^2 \psi_2) + T_{12}(\mathbf{r}) (\psi_1^{\dagger} \psi_2 + h.c.).$$

Harmonic oscillator flat bands  

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$$\oint \underbrace{\psi_{\pm} = \frac{1}{\sqrt{2}} (\psi_1 \pm \psi_2)}_{H_{\pm}} = \frac{1}{2m^*} (\psi_{\pm}^{\dagger} \partial^2 \psi_{\pm}) \pm T_{12}(\mathbf{r}) \psi_{\pm}^{\dagger} \psi_{\pm}.$$

$$H_{\pm} = \psi_{\pm}^{\dagger} \left( \frac{1}{2m^*} \partial^2 \pm \frac{1}{2} m^* \omega^2 r^2 \right) \psi_{\pm}.$$

$$\omega = \pi \Theta L \sqrt{2T_0 T_1} = \omega_{\Theta} \Theta$$



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-1

$$\frac{\partial^2 T(\mathbf{r})}{\partial \mathbf{r}^2} = \Theta \frac{\partial^2 T(\mathbf{d})}{\partial \mathbf{d}^2}$$

$$\omega = \omega_{\Theta}\Theta = \Theta \left(\frac{\partial^2 E(\mathbf{k})}{\partial \mathbf{k}^2}\right) \left(\frac{\partial^2 T(\mathbf{d})}{\partial \mathbf{d}^2}\right)$$



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$$\omega = \omega_{\Theta} \Theta = \Theta \left( \frac{\partial^2 E(\mathbf{k})}{\partial \mathbf{k}^2} \right) \left( \frac{\partial^2 T(\mathbf{d})}{\partial \mathbf{d}^2} \right)$$

Loss of confining well → No confined levels

### **Configuration-Momentum Duality**

 $LDoS(\mathbf{d}) = \sum |\psi_{\mathbf{k}}(\mathbf{d})|^2$  $\mathbf{k}$ 

## **Configuration-Momentum Duality**



Momentum-projected local density of states, averaged over all interlayer configurations

#### **Configuration-Momentum Duality**



#### The other harmonic failure

$$\omega = \omega_{\Theta}\Theta = \Theta\left(\frac{\partial^2 E(\mathbf{k})}{\partial \mathbf{k}^2}\right)\left(\frac{\partial^2 T(\mathbf{d})}{\partial \mathbf{d}^2}\right)$$









## **Twistronic classification**



#### Momentum crystal in real-space



## Momentum crystal in real-space



Commensurate



Incommensuration parameter:

$$\Theta = \Theta_0 \times (1 + \Delta)$$

# Momentum crystal in real-space





Incomm.



Incomm.



Incommensuration parameter:

$$\Theta = \Theta_0 \times (1 + \Delta)$$

Momentum Crystal is analogous to the localization of a 1D TBH in an incommensurate potential

#### 2D Example: Bilayer Graphene







Large DOS enhancements at AA stacking For low-energy TBG, bands are likely a better approach!

What about high energy?





Lots of confined modes in metallic background, even above "magic angle" No transport... but possible optical experiments (exciton spectrum?)

# 2D Example: Bilayer MoS<sub>2</sub>











# Tight-binding supercells $\theta = 2.28^{\circ}$ $\theta = 5.09^{\circ}$











 $AA\,AB\,BA\,AA \quad AA\,AB\,BA\,AA \quad AA\,AB\,BA\,AA$ 







# Summary

- 1) Introduced a framework for predicting moire electronic effects
- 2) Explored microscopic details of twistronics
- 3) Momentum-configuration duality in twisted bilayers
- 4) Studied examples in realistic 2D systems

- Look for simultaneous flat bands
- Metallic systems with flat bands
- Observable momentum crystal
- "By eye" predictions (machine learning?)



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